REMARKS

Claims 1-15 and 18-20 are pending in the above-identified application. Claims 1, 5, and

20 are amended. Claims 2-4, 6, 7, 9, 10, 13, and 14 are cancelled. Claims 18 and 19 are

withdrawn. No new subject matter is added. It is respectfully submitted that this response is

fully responsive to the Office Action dated June 14, 2005.

Claims 1-15 and 20 were rejected under 35 U.S.C. §103(a) as being unpatentable over

Smith et al. (U.S. 2004/0026031 A1) in view of Suenaga et al. (U.S. 6,569,696 B2), Anai et al.

(U.S. 6,458,208 B1) and Shimane (U.S. 2003/0017256 A1). Applicant amends claims 1, 5, and

20 for clarification purposes. In view of the amendments and the following remarks, Applicant

respectfully requests that the Examiner withdraw the rejections and allow all pending claims.

The Examiner asserted that Shimane teaches that the temperature of the resist and

ambient humidity are preset in order to obtain optimum conditions. Thus, the Examiner argued

that it would be obvious to one of ordinary skill in the art to combine the teachings of Smith et

al., Suenaga et al. and Anai et al. with the teachings of Shimane to enable independently

controlling the temperature and humidity conditions of the resist deposition unit of Smith et al.,

Suenaga et al. and Anai et al.

However, in the present invention, the resist is applied onto the substrate in a humid

atmosphere controlled to have a prescribed room temperature and a prescribed humidity so as to

suppress fluctuation of a moisture amount on the substrate surface and thus to make a moderate

amount of moisture reproducibly exist on the substrate surface. By such controls of the

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temperature and the humidity of the humid atmosphere, the present invention realizes the formation of the resist film having a uniform thickness with high reproducibility. *Shimane*, on the other hand, neither teaches nor suggests such specific controls of the temperature and the

Furthermore, the present invention has a feature that the substrate is carried to the step of

humidity of the humid atmosphere in the step of applying the resist on the substrate.

thermal processing, and from the step of thermal processing to the step of making the surface of

the substrate hydrophobic through a carrying compartment with a third dehumidified atmosphere

therein. The carrying compartment corresponds to the arm moving region 26 in the embodiment.

Not only the steps of thermal processing and making the surface of the substrate hydrophobic

themselves but also the steps of carrying the substrate are performed in the dehumidified

atmosphere in the present invention. In addition, the substrate is carried to the step of thermal

processing, and from the step of thermal processing to the step of making the surface of the

substrate hydrophobic through the same one compartment. The substrate is carried in the same

compartment with the dehumidified atmosphere therein, whereby the substrate can be efficiently

transferred to the step of thermal processing and to the step of making the substrate surface

hydrophobic, excluding the influences of the moisture to said steps. Accordingly, the generation

of foreign substances on the surface of the substrate can be effectively suppressed without the

decrease of the throughput of the method and the complication of the method.

The Examiner argues that it would have been obvious that the atmosphere has to be

dehumidified through the step of thermal processing to the step of making the substrate surface

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hydrophobic in consideration of the objective during the steps. However, even if the objective

during the steps is taken into consideration, it cannot be obvious that the substrate is carried

between the steps through the same carrying compartment with a dehumidified atmosphere

therein, integrating the steps through the carrying compartment. It is also evident that the

combined teachings of the cited references neither teaches nor suggests such a specific carrying

path of a substrate through the same compartment with a dehumidified atmosphere therein in a

resist applying method.

As discussed above, even if the teachings of the cited prior art were combined, the present

invention according to claims 1, 20 and dependent claims 5, 8, 11, 12 and 15 would not have

been obvious to one of ordinary skill in the art at the time the invention was made. Accordingly,

Applicant respectfully requests that the rejection of these claims be withdrawn.

In view of the aforementioned amendments and accompanying remarks, Applicant

submits that the claims, as herein amended, are in condition for allowance. Applicant requests

such action at an early date.

Should the Examiner deem that any further action by applicant would be desirable to

place the application in condition for allowance; the Examiner is encouraged to telephone

applicant's undersigned attorney.

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Amendment Under 37 C.F.R. §1.111 Serial No. 10/652,314 Attorney Docket No. 031098

If this paper is not timely filed, Applicant respectfully petitions for an appropriate extension of time. The fees for such an extension or any other fees that may be due with respect to this paper may be charged to Deposit Account No. 50-2866.

Respectfully submitted,

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